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Vanadium Oxide Monolayer Catalysts. 3. A Raman Spectroscopic and Temperature-Programmed Reduction Study of Monolayer and Crystal-Type Vanadia on Various Supports^{1,2}

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Vanadium(V) oxide supported on γ -Al₂O₃, CeO₂, Cr₂O₃, SiO₂, TiO₂, and ZrO₂ was studied by X-ray fluorescence, by X-ray diffraction, and especially by the combination of Raman spectroscopy and temperature-programmed reduction (TPR) for qualitative and quantitative structural analysis, respectively. Catalysts were prepared via ion-exchange and wet-impregnation methods. The V contents ranged from ~1 to 40 wt % V. At low surface concentrations only surface vanadate phases of two-dimensional character are observed for all carriers. According to Raman and TPR data the structure of these surface vanadate species is independent of the preparation technique. At medium and high surface concentrations, the wet-impregnated samples already contain crystalline V₂O₅. At equal surface concentrations the ion-exchanged catalysts contain no V₂O₅ crystallites. An exception is SiO₂ on which also crystalline V₂O₅ is formed in both preparation techniques. Monolayer stability toward thermal treatment decreases in the order Al₂O₃ > TiO₂ > CeO₂, whereas on heating ion-exchanged V/SiO₂ the crystalline V₂O₅ spreads out over the silica surface. The reducibilities of the ion-exchanged catalysts, as measured by TPR, can be used as a measure for the contact interaction between vanadia and the carrier oxides. At temperatures of 500–800 K, this interaction ranges from strong with titania to weak with silica as a carrier.

Introduction

Vanadium oxides are widely used as catalysts in oxidation reactions, e.g., the oxidation of sulfur dioxide, carbon monoxide, and hydrocarbons.^{3,4} When supported mostly on oxidic supports are used.

The existence of different surface vanadium oxides on various supports has been the subject of several studies.^{1,2,5-14} In general the influence of parameters such as the method of preparation, the nature of the support, the concentration of active component, and the thermal treatment on the structure of the catalyst and its catalytic behavior has been studied.

Recent publications show that Raman spectroscopy is a valuable technique in catalytic research. It was used by, among others, Brown et al.,¹⁵ Medema et al.,¹⁶ and Knözinger and Jeziorowski^{17,18} in the identification of supported molybdenum oxide species, whereas tungsten oxide supported on silica or alumina was studied by Thomas et al.^{19,20} In a previous paper² on vanadium oxide/ γ -Al₂O₃, it was shown, however, that Raman spectroscopy cannot be used for quantitative determination of the different surface and bulk phases: V₂O₅ crystallites are considerably more Raman active than the surface phases, whereas the surface phases themselves may also differ in Raman activity. Similar results were reported for supported molybdenum¹⁹ and tungsten²¹ oxide catalysts.

With respect to quantitative analysis, temperature-programmed reduction (TPR) has proved to be a more appropriate tool.²²⁻²⁵ Moreover this technique gives information about the reducibility of the different supported phases as well as of the supports, and the observed reducibilities

might be related directly to catalytic oxidation reactions.

In this study, besides Raman spectroscopy and TPR, X-ray diffraction (XRD) and X-ray fluorescence were used to determine crystallite size and vanadium content, respectively. Table I summarizes the catalyst systems prepared in this study.

Two types of catalysts were studied. The first type was prepared by wet impregnation of γ -Al₂O₃, SiO₂, and TiO₂. The second type was prepared by adsorption of polymeric and/or monomeric vanadate ions from aqueous solution on the carriers.^{1,2} In this process anionic exchange of these ions with the surface hydroxyl groups of the carrier oxides (γ -Al₂O₃, CeO₂, Cr₂O₃, SiO₂, TiO₂, and ZrO₂) plays an important role as shown by the pH change of the eluate.¹ The thermal stability of the latter type of catalysts was studied by Raman spectroscopy after heat treatment to 1073 K in oxygen flow for 2 h.

Results of this study will be used in the near future in correlating the structural aspects with catalytic behavior in CO oxidation and other oxidation reactions.

Experimental Section

Materials. γ -Al₂O₃, SiO₂, and TiO₂ were obtained from Degussa; CeO₂, Cr₂O₃, and ZrO₂ were prepared as described by Fransen et al.²⁶

The V₂O₅ used was a Baker product (analytical grade). Ammonium metavanadate (Merck, analytical grade) was used for wet impregnation of the carrier materials. ZrV₂O₇ and CeVO₄ used as reference compounds in structural analysis were prepared as follows. ZrO₂ and CeO₂ were each mixed in a ball mill with a stoichiometric quantity of V₂O₅ and heated at 973 and 673 K, respectively, for 168 h. In order to remove traces of unreacted V₂O₅, we treated the samples with an ammonia solution.²⁷ X-ray diffraction showed only the diffraction lines of the pure compounds. The composition was checked by X-ray fluorescence.

Catalyst Preparation. Two preparative methods were applied, the first one being a one-step wet impregnation

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TABLE I: Survey of Catalysts

catalyst series	preparation method ^a	range of V contents, ^b wt % V	notation in text	BET surface area of carrier, m ² g ⁻¹	theoretical surface coverage, ^{b,c} V atoms nm ⁻²
V oxide/ γ -Al ₂ O ₃	w	0.5–38.3	V(0.5–38.3)/Al-w	78	0.8–184.0
	i	6.8	V(6.8)Al-i		11.7
V oxide/CeO ₂	i	5.3	V(5.3)/Ce-i	48	14.4
V oxide/Cr ₂ O ₃	i	0.6	V(0.6)/Cr-i	20	3.6
V oxide/SiO ₂	w	1.4–39.8	V(1.4–39.8)/Si-w	300	0.6–54.4
	i	1.2	V(1.2)/Si-i		0.5
V oxide/TiO ₂	w	1.4–47.1	V(1.4–47.1)/Ti-w	45	3.8–787
	i	1.7	V(1.7)/Ti-i		4.6
V oxide/ZrO ₂	i	4.3	V(4.3)/Zr-i	107	5.1

^a w = wet-impregnated and i = ion-exchange. ^b Lower and upper limit of each w series. ^c In crystalline V₂O₅ the (010) face contains 9.7 V atoms per nm², corresponding to 0.103 nm² per VO_{2.5} unit.⁹

of the supports using aqueous solutions of ammonium metavanadate. In the second one a freshly prepared solution of 1 wt % NH₄VO₃ with pH 4 was passed through a bed of support. For details see elsewhere.¹

Subsequently the catalysts were dried at 383 K (17 h) and calcined at 723 K (2 h).

X-ray Fluorescence. The vanadium content of each catalyst was determined on a Philips 1410 X-ray spectrometer after a borax fusion pretreatment.²⁸

X-ray Diffraction. Some catalyst samples (impregnated series on γ -Al₂O₃, SiO₂, and TiO₂) were analyzed on a Philips PW 1050-25 vertical diffractometer.

Raman Spectroscopy. Raman spectra were recorded as described previously.²

Temperature-Programmed Reduction. Catalyst samples of such a size that they contained $\sim 2 \times 10^{-5}$ mol of vanadium were reduced in a quartz tube (4.5 mm i.d.) in a dried H₂/N₂ gas mixture with 66 vol % H₂.

All samples were pretreated by calcination at 823 K in dry air for 1 h and subsequently cooled under vacuum to 473 K. The flow rate of the H₂/N₂ gas mixture was 18 mL (NTP) min⁻¹, while the tubular furnace was linearly heated from 473 to 1330 K with a heating rate of 5 K min⁻¹. If necessary, the furnace was kept isothermally at the final temperature to complete the reduction. In order to check for possible mass transport limitations, we carried out some measurements at a heating rate of 10 K min⁻¹. Hydrogen consumptions were determined according to the method described by Jenkins et al.²³ Calibration of the TPR apparatus enabled a quantitative thermoanalytical determination of the different phases.

Results and Discussion

Wet-Impregnated Catalysts. V/ γ -Al₂O₃. A Raman study of vanadium(V) oxide/ γ -Al₂O₃ samples, prepared by wet impregnation, was reported earlier.² It was found that at low coverages two broad Raman bands were present. One band around 970 cm⁻¹ was assigned to a two-dimensional polymeric network of distorted octahedra sharing corners and/or edges and seemed to decrease in intensity from 0.5 to 2.1 wt % V in favor of another band around 830 cm⁻¹. The latter was attributed to isolated VO₄ tetrahedra on the surface. At higher concentrations (from 3.7% V) V₂O₅ crystallites were observed.

The same phenomena are well reflected by the TPR profiles of the same catalyst series as shown in Figure 1. At low coverages (i.e., up to 2.1 wt % V) only one peak around 650–700 K is observed. From 2.1 wt % V to 7.1 wt % V on the low-temperature side of this peak, a new signal appears, first as an increasing asymmetry and finally as an extra peak or shoulder around 600 K. At increasing V content these peaks shift toward lower reduction tem-

Figure 1. TPR profiles of impregnated vanadium(V) oxide/ γ -Al₂O₃ catalysts and of unsupported V₂O₅. The V contents as determined from TPR peak surface areas are given in parentheses.

peratures. Similar, even more pronounced shifts to lower temperatures were reported for alumina-supported molybdenum oxide catalysts which show a shift of the peak due to octahedral surface molybdate from 1150 to as low as 850 K.²⁵ Probably this shift is caused by the heterogeneity of the adsorption sites at the alumina surface and/or the higher degree of polymerization of the species at increasing V content.

By analogy with a study on alumina-supported molybdena,¹⁶ one might expect to observe at first isolated vanadate tetrahedra at low surface coverages and an octahedral polyvanadate phase at higher surface coverages. Neither from Raman spectroscopy² nor from TPR (Figure 1) can this be concluded definitely. Both techniques point

Figure 2. X-ray diffraction patterns of impregnated vanadium(V) oxide/ γ - Al_2O_3 catalysts and of supported V_2O_5 .

to even more polyvanadate octahedra at the lower coverages than vanadate tetrahedra. The dominance of octahedral over tetrahedral coordination seems also present on supported molybdenum and tungsten oxide.^{16,19,20} Moreover this dominance depends on the carrier used and seems to decrease in the order $\text{V} > \text{W} > \text{Mo}$. Apparently for supported molybdenum oxide systems the results are conflicting. Probably the occurrence of tetrahedral molybdate at low coverages depends on the specific characteristics of the carrier used. Further, it cannot be excluded that certain preparation methods as ion exchange and wet impregnation result in a different distribution of the metal ions over tetrahedral and octahedral coordination.²⁹

Thus it is likely that octahedral polyvanadate structures are being formed prior to or at least simultaneously with the formation of tetrahedral vanadate species of lower degree of polymerization. A study is in progress to elucidate the nature of the species formed as a result of ion exchange and their possible structural changes on calcination.

From the correspondence with Raman spectroscopy, the TPR peak around 650 K is assigned to a two-dimensional octahedral polyvanadate surface structure, and the extra peak or shoulder around 600 K to a tetrahedral vanadate structure.

From 3.7 wt % V a third peak beyond 700 K is observed coinciding with the appearance of Raman lines due to crystalline V_2O_5 .² With increasing V coverage this peak shifts to higher temperatures up to the reduction temperature of pure V_2O_5 . In order to investigate whether water as a reduction product causes the increase in reduction temperature, we recorded some profiles with a water saturator placed directly before the sample furnace. This caused no shifts in the reduction profiles. It seems more likely that the shift is caused by an increasing V_2O_5 crystallite size, reflected by the decreasing XRD line widths (Figure 2). This is in agreement with the findings of Tilley and Hyde.³⁰ In a study of the reduction of V_2O_5 in an optical microscope, they found that the rate of reduction increases with decreasing crystal dimensions in the crystallographic c direction. It is likely that the relation between rate of reduction and crystal dimension in a certain crystallographic direction holds also for supported systems. This crystallographic direction, however, need not necessarily be the c direction.

Thus crystal size, combined with crystal orientation, may play an important role in reduction behavior. The observation (Figure 1) that unsupported V_2O_5 reduces at a higher temperature than alumina-supported crystalline V_2O_5 present in V(38.3)/Al-w (with comparable XRD line

Figure 3. TPR profiles of impregnated vanadium(V) oxide/ γ - Al_2O_3 and of unsupported V_2O_5 , recorded at a linear heating rate of 10 K min^{-1} .

width, so equal crystal size) supports this idea. Unsupported V_2O_5 probably has a random orientation of various crystallographic planes exposed to reduction, whereas supported V_2O_5 may display a preferred orientation with better reducibility, for example, (010) V_2O_5 lamellae on top of the carrier.^{9,31}

The difference in reduction behavior is also illustrated by Figure 3: some samples were reduced at a heating rate of 10 K min^{-1} . It is remarkable that the reduction peaks of all samples shift to a higher temperature except for unsupported V_2O_5 . Although the reasons for these shifts are not yet completely understood, it can be concluded that the high-temperature peak shown in Figure 1 is correctly assigned to V_2O_5 . The better reducibility of the V-(38.3)/Al-w, compared to unsupported V_2O_5 with a comparable crystallite size may be caused by support-induced crystal orientations. Further observations reveal that the vanadium contents, determined from the TPR peak areas, correspond very well with those determined by XRF. (This holds for all vanadia catalysts studied.) The above findings are demonstrated by the data shown in Figure 1. In the calculation it is assumed that the hydrogen consumption is one H_2 molecule per V atom. The agreement with the XRF data confirms that vanadium is, indeed, reduced from pentavalent to trivalent ions.

As mentioned previously² the relative intensities of the Raman bands due to crystalline V_2O_5 and to the vanadate surface structures are misleading. Combination of the Raman and TPR peak surface areas shows that in vanadia/ γ - Al_2O_3 catalysts crystalline V_2O_5 is 5–10 times more

Figure 4. Relation between Raman intensity ratio and TPR intensity ratio of octahedral and tetrahedral surface vanadate to crystalline V_2O_5 for impregnated vanadium(V) oxide/ γ - Al_2O_3 .

Raman active than the surface compounds (see Figure 4).

V/SiO_2 . From the TPR profiles presented in Figure 5, similar conclusions are drawn as in the V/γ - Al_2O_3 case. Two peaks are observed again, one around 700 K and another at 700–780 K which can be assigned to some surface phase(s) and a crystalline V_2O_5 phase, respectively. In contrast to V/γ - Al_2O_3 catalysts (Figure 1), no shifts of the former peak are observed when increasing the surface coverage; this is analogous to silica-supported molybdena.²⁵ Figure 7 shows that in XRD the crystalline phase is only observed at coverages exceeding 4.6 wt % V, whereas the shoulder on the high-temperature side of the TPR peak recorded for the $V(2.3)/Si$ -w sample indicates that V_2O_5 crystals are also formed at lower coverages.

From the Raman spectrum in Figure 5, it can be seen that, even in the $V(1.4)/Si$ -w sample, crystalline V_2O_5 is present. (V_2O_5 has Raman bands around 996, 703, 530, 483, 406, 306, and 285 cm^{-1} .³²) When the V content is increased, these bands become gradually sharper, indicating that the V_2O_5 crystals formed have no well-defined structure up to 4.6 wt % V, which is in agreement with the results of XRD analysis in Figure 7.

At first sight the Raman bands around 1020, 900, 830, and 650 cm^{-1} seem to correspond to the TPR peak around 700 K. It was argued earlier² that the broad band around 830 cm^{-1} , observed at 1.4, 2.3, and 4.6 wt % V, can be ascribed to a surface phase with tetrahedrally coordinated vanadium ions. A corresponding TPR peak (expected around 650 K) is hardly observable in the profiles of Figure 5. This indicates that only a minor amount of tetrahedrally coordinated V ions is present. The other bands at 1020, 900, and 650 cm^{-1} are assigned to polymeric arrays of VO_6 octahedra. These Raman bands correspond with one single TPR peak at 700 K, indicating that the structure of the octahedral polyvanadate phases does not change significantly when the V content is increased.

Figure 5. Raman spectra (a) and TPR profiles (b) of impregnated vanadium(V) oxide/ SiO_2 .

V/TiO_2 . On *titania* the situation is comparable. At 4.2 wt % V crystalline V_2O_5 is recorded in TPR (Figure 6) as a peak around 700–750 K, in XRD as small crystallites (Figure 7), and in Raman spectroscopy as sharp lines at 996 and 703 cm^{-1} .³² At lower coverages two TPR peaks are observed at 600–650 K (or as one peak with a shoulder), corresponding to Raman bands at 980–990 and 920–930 cm^{-1} . It is rather difficult to correlate these Raman bands with the peaks in TPR. Moreover it cannot be concluded whether there is a tetrahedral vanadate phase (band around 830 cm^{-1}) because of the presence of an interfering rutile band at 826 cm^{-1} .³² The other TiO_2 Raman bands lie at 612 and 447 cm^{-1} (rutile) and around 640, 515, and 400 (anatase).³² The composition of the titania was determined from its XRD pattern (Figure 7), which yields 65% anatase and 35% rutile.

The presence of TiO_2 bands in the Raman spectra makes it possible to estimate the penetration depth of the incident laser light. Figure 8 shows the resulting titania bands when the recorded spectra are corrected for vanadium oxide bands and standardized for sensitivity. It is seen that the intensities of the TiO_2 bands are reduced by a factor of 6 when the support is covered with 6.3 wt % V. From the TPR profile in Figure 6 it follows that at 6.3 wt % V about 50% of the vanadium oxide is present as V_2O_5 crystallites, and 50% (i.e., 3.15 wt % V) as a surface phase. The latter phase will be present as a two-dimensional monolayer, as can be calculated from the amount of vanadia involved (~ 3.15 wt % V) and the BET surface area of 40 $m^2 g^{-1}$, yielding 10.3 $\text{\AA}^2$ per V oxide unit. In crystallized V_2O_5 , which has a lamellar structure,³³ the calculated surface area per $VO_{2.5}$ unit in the (010) plane is exactly 10.3 $\text{\AA}^2$.⁹ Thus, as a model, the 6.3 wt % V consists of 3.15 wt % V as a monolayer array together with an equal amount of vanadia as very small crystallites. This is illustrated schematically in Figure 8.

The V(38.2)/Ti-w sample may thus consist of a monolayer array with a greater number of somewhat larger crystallites than the one supposedly present in V(6.3)/Ti-w. Here, a major increment in V content reduced the intensity of the titania spectrum only by a factor of 4. Thus crystalline V_2O_5 , when present as small crystallites which do not fully cover the surface, cannot "shield" the underlying outer TiO_2 layers. As a consequence the main contribution to "shielding" is performed by the monolayer phase.

When the crystallites grow, the effective shielding of underlying TiO_2 layers is increased, especially when they cover the surface to a greater extent. This is demonstrated in Figure 8 in the transition from 38.2 to 47.1 wt % V. In this case a minor increment in V content reduces the titania spectrum by a factor of 4.

In conclusion it may be stated that the scattered laser light intensity is reduced by a factor of 5–6 after passing through one fully dispersed monolayer with a thickness of ~ 4 $\text{\AA}$.

If one compares the characteristic Raman lines of crystalline V_2O_5 on silica and titania with the corresponding spectrum of pure V_2O_5 , the following interesting phenomena can also be observed: although the positions of these lines are the same, their relative intensities are not. Similar effects were found for vanadium oxide on alumina, and a tentative explanation for this was proposed earlier.² A more precise explanation of this observation may be that, because of the presence of small to medium-sized crystallites interacting with the support surface, the selection rules for vibrational transitions are changed, leading to the changes in the intensities. Again crystal form and orientations seem to play a role.

Figure 6. Raman spectra (a) and TPR profiles (b) of impregnated vanadium(V) oxide/ TiO_2 .

Figure 7. X-ray diffraction patterns of impregnated vanadium(V) oxide on SiO_2 and TiO_2 and of unsupported V_2O_5 .

Figure 8. Raman spectra of the TiO_2 carrier in a series of impregnated vanadium(V) oxide/ TiO_2 . Spectra are corrected for vanadium oxide and standardized for sensitivity. The spectrum of pure TiO_2 has been scaled down by a factor of 5.

Ion-Exchanged Catalysts. The TPR profiles of the catalysts, prepared by ion-exchange,¹ and those of the pure carrier oxides are presented in Figure 9, and Figure 10 shows some corresponding Raman spectra of samples treated at different calcination temperatures (2 h in oxygen flow).

V/ Cr_2O_3 . The TPR profile of vanadia/chromia shows a multiple-step reduction of the chromia at temperatures markedly lower than that of the vanadium oxide. Since this reduction occurs at 650 K, it is concluded that the vanadium oxide is present as a surface phase and not as

Figure 9. TPR profiles of catalysts, prepared by ion exchange, and of their corresponding supports.

crystalline V_2O_5 which reduces above 700 K for all catalyst systems used in this study. The reduction of vanadium oxide, however, is obscured by that of chromia itself. It is therefore difficult to study the influence of a chromia

Figure 10. Raman spectra of ion-exchanged catalysts after calcination at different temperatures for 2 h in oxygen flow.

carrier on the catalytic activity of the supported vanadia.

V/SiO₂. The TPR profile and Raman spectrum (723 K calcination temperature) of vanadia/silica, i.e., V-(1.2)/Si-i are similar to those of the V(1.4)/Si-w. Thus, also here a dispersed surface phase is present on the silica together with crystalline V₂O₅, reflecting the low affinity between silica and vanadia. This weak affinity was already mentioned previously¹ where it was shown that on silica the coverage remained far below its theoretical monolayer capacity ($\theta \approx 0.05$). The influence of the vanadate-silica interaction and the degree of dispersion increase on calcining at higher temperatures (Figure 10). The Raman lines of V₂O₅ at 996 and 703 cm⁻¹ disappear while especially the band around 1020 cm⁻¹ increases. The V content was verified to be 1.2 wt % V before and after calcination. This indicates that no loss of V₂O₅ due to sublimation had taken place. Apparently the crystalline V₂O₅ with its layer structure depolymerizes at temperatures near its melting point (943 K). These observations are in agreement with the results of Hanke et al.⁹ and Horvath et al.¹⁰ It is clear that these thermal effects cannot be studied by TPR, as the reduction is already completed at 800 K.

V/ γ -Al₂O₃. The TPR profile of V(6.8)/Al-i shows two peaks at exactly the same positions (600 and 650 K, respectively) as that of wet-impregnated vanadia/alumina with the same V content. However, now the peak at 700 K due to crystalline V₂O₅ is completely absent, which points to complete monolayer coverage with a tetrahedral and a polymeric octahedral vanadate phase (TPR peaks at 600 and 650 K, respectively). Moreover it shows that our previous assignment of the peak around 700 K to V₂O₅ crystals is correct. Thus, Raman spectroscopy and TPR can be added to the techniques suitable for establishing the presence of a monolayer proposed by Fransen et al.²⁶

The thermal behavior of the two surface phases is presented in Figure 10. Drying at 373 K results in a monolayer phase with bands around 980 cm⁻¹ (octahedral polyvanadate) and 840–850 cm⁻¹ (tetrahedral vanadate). Both bands are present after calcination at 873 K (2 h), reflecting the thermal stability of these monolayer species up to this temperature. Heating at 1073 K results in sharp lines at 996, 703, and 530 cm⁻¹, characteristic for crystalline V₂O₅. This is in agreement with the findings of Brandt,³⁴ who studied the interaction of vanadia and alumina and found that at 873 K an interaction compound is formed (AlVO₄) whereas above 953 K it decomposes in both oxides.

V/TiO₂. The TPR profile of vanadia/titania, V(1.7)/Ti-i, is identical with that of wet-impregnated titania, and the same applies to its Raman spectrum. Bands arising from the presence of some surface phase(s) are observed around 980–990 cm⁻¹ and 920–930 cm⁻¹, and the corresponding TPR peak has a maximum at 600 K. On the vanadia-covered catalyst dried at 373 K a Raman band is observed around 1050 cm⁻¹ (Figure 10), which is assigned to a δ_{OH^-} vibration mode of hydroxyl groups from the vanadate anions because this is not observed on pure TiO₂. This δ_{OH^-} band disappears on further calcination. At 873 and 1073 K the other two bands around 990 and 930 cm⁻¹ gradually disappear. Moreover the anatase bands (640, 515, and 400 cm⁻¹) decrease in intensity, whereas those of rutile (612 and 447 cm⁻¹) increase.

These observations are in agreement with the findings of Vejux and Courtine,³¹ that heat treatment of vanadia/titania (anatase) catalysts above 823 K leads to the formation of solid solutions of vanadium ions (in reduced V⁴⁺ state) in rutile. They suggested both the V₂O₅ reduction and the phase transformation from anatase into

rutile to be topotactic reactions, activated by the remarkable fit of the oxidic crystallographic patterns in contact at the V_2O_5 - TiO_2 interface. As a consequence, the ease of reduction of vanadia in monolayer contact with a carrier (see Figure 9) may reflect the degree of (mis)fit of the respective structures at the interface, ranging from good on titania (VO_2 being isostructural with rutile TiO_2) to poor on silica. Also from catalytic experiments we found evidence for the dissolution of vanadium ions into the TiO_2 matrix.³⁵

V/ ZrO_2 . The TPR profiles of vanadia/zirconia and vanadia/alumina are very similar: the same shape and peak positions, indicating that at least two surface phases are present. The Raman spectra of different zirconia-supported catalyst samples are presented in Figure 10. The sharp peak at 1050 cm^{-1} for pure zirconia points to the presence of a large amount of hydroxyl groups, originating from $ZrO(OH)_2$ which is also formed in the preparation of zirconia.³⁶ The disappearance of this peak as a result of vanadate deposition and drying at 373 K confirms the idea that ion exchange of hydroxyl groups with vanadate species takes place, giving rise to a strong and broad band around 790 cm^{-1} with a shoulder at 980 cm^{-1} . The "shielding" of the ZrO_2 bands reveals that the vanadium oxide is very well dispersed over the surface. The 790 cm^{-1} band is assigned to a vanadium oxide species with tetrahedral coordination, which may also be rather distorted.

Calcination at 873 K and higher leads to the disappearance of these two bands and the appearance of bands around 992, 780, 700, 525, 470, and 380 cm^{-1} . The two main peaks (992 and 780 cm^{-1}) are also present in the spectrum of ZrV_2O_7 , as is the minor peak around 525 cm^{-1} . This indicates the formation of a ZrV_2O_7 phase. The peak at 700 cm^{-1} may point to a coexisting V_2O_5 phase, possibly resulting from thermal decomposition of the ZrV_2O_7 into zirconia and vanadia or from formation of a solid solution.³⁷

V/ CeO_2 . When vanadia is supported on ceria, weak Raman scattering between 800 and 1000 cm^{-1} may point to some vanadium oxide phase which either is incorporated into the ceria lattice or has a much lower Raman activity than cerium oxide, which shows only one band at 468 cm^{-1} . (This is, however, very strong and sharp.³¹) There is no indication for the presence of a phase like $CeVO_4$, which has a different spectrum (Figure 10).

Here, TPR gives more information. From Figure 9 it can be seen that the reduction of pure CeO_2 takes place in two steps and starts from 500 K. When covered with vanadium oxide this reduction starts at higher temperatures. Also the catalytic activity for CO oxidation decreases, whereas for all other ion-exchanged catalysts it increases.³⁴ The reduction peak at 650 K on top of these ceria reduction peaks can be assigned to some surface or dissolved vanadia phase(s). It is unlikely that crystalline V_2O_5 is among these phases because its TPR peak lies around 700 K.

Roozeboom et al.² reported earlier that a dark coloration of the surface vanadate is observed upon irradiation by laser light. In all ion-exchanged catalysts presented in Figure 10 this coloration took place, even when the samples were rotated. Two possible explanations (polymerization and reduction of the vanadate surface species) were discussed in part two of this series.² It is not yet clear whether this is caused by thermal or photochemical effects.

Concluding Remarks

Crystalline V_2O_5 is detected at relatively high V contents by XRD on $\gamma\text{-Al}_2\text{O}_3$, SiO_2 , and TiO_2 -supported catalysts prepared via wet impregnation. At lower contents it is

readily detected by Raman spectroscopy and by TPR, together with some surface vanadate species of two-dimensional character.

On ion-exchanged catalysts supported on $\gamma\text{-Al}_2\text{O}_3$, CeO_2 , Cr_2O_3 , TiO_2 , and ZrO_2 , only these monolayer species are detected by Raman spectroscopy as well as by TPR. An exception is SiO_2 , on which also crystalline V_2O_5 is found.

Raman spectroscopy enables only a *qualitative* analysis of the crystalline V_2O_5 and the respective vanadium(V) surface phases. TPR enables a *quantitative* analysis, provided that Raman bands and TPR peaks can be correlated to each other.

Raman spectroscopy gives valuable additional information about structural changes which occur as a result of heat treatment, e.g., during application in a catalytic process. Thus Raman spectra of ion-exchanged catalyst samples heated at increasing temperatures (373–1073 K) show that monolayer existence is limited and that (1) on $\gamma\text{-Al}_2\text{O}_3$ the vanadia monolayer structures do not change markedly, (2) on titania a solid solution is formed, (3) on zirconia there is ZrV_2O_7 formation, and (4) on ceria apparently small amounts of surface species are present.

TPR also gives information about a catalyst as to its reducibility which can be coupled to its catalytic behavior in reduction-oxidation reactions and to the degree of contact interaction at the interface of vanadia and the respective supports. Better contact seems to enhance the reducibility.

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Catalytic Oxidation of Furan on a Mo-Ti-O Catalyst. Infrared and Thermodesorption Study

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The catalytic oxidation of butenes produces maleic anhydride in a multistep reaction, in which furan is one of the intermediates. In order to study the mechanism of this reaction, we have investigated the adsorption of furan on a selective catalyst (Ti-Mo-O). Two modes of adsorption were observed, and it appears that the Mo=O bond in the catalyst does not play any role in the formation of maleic anhydride.

Introduction

Among oxidation reactions on heterogeneous catalysts the selective transformation of butene can be of major interest as a substitute of benzene in maleic anhydride production. The reaction mechanism for the oxidation of 1-butene has been extensively studied over, principally, V_2O_5 based catalysts;^{1,2} various intermediates, which appear in the gas phase during the reaction, are well identified^{1,3,4} (successively: butadiene, crotonaldehyde, furan, and the final product). Nevertheless the various adsorbed states are ill-defined, and the role of gaseous oxygen is not well understood.

In order to understand what occurs in the adsorbed state, we have studied the adsorption of furan on a Mo-O₃-TiO₂ catalyst, since it is the last known intermediate product in the oxidation of 1-butene into maleic anhydride. Adsorption was followed at various temperatures by means of infrared spectroscopy and thermogravimetric desorption.

Experimental Section

Catalyst. The MoO₃-TiO₂ catalyst used in this work was the same as that already studied in our laboratory for the catalytic conversion of 1-butene to maleic anhydride.⁵ It was prepared according to the method recommended by Courty et al.⁶ for the synthesis of mixed oxides of known composition. All of the experiments were carried out by using a catalyst containing 15.6 atom % of molybdenum; its specific surface area was 74 m² g⁻¹. Previous experiments have shown that this catalyst is active and selective for the catalytic conversion of 1-butene into maleic anhydride⁵ (53% maleic anhydride at 60% conversion).

Before use, the powder was pressed into a wafer 18 mm in diameter weighing ~50 mg under a pressure of 2 ton cm⁻².

Before the adsorption experiments were carried out, the sample of catalyst was oxidized in air for 15 h at 450 °C, followed by outgassing (10⁻⁵ torr) for 1 h at this temperature and for 2 h at room temperature.

Products. All of the products used were of commercial origin having a purity better than 98%. They were used after outgassing and drying on a 13× molecular sieve.

Infrared Studies. A wafer of catalyst was fixed on a support made of titanium foil, allowing a rapid cooling of the sample even under vacuum. This support was introduced into a cell consisting of a 60-cm long cylindrical Pyrex tube equipped with two KBr windows at one end while the other end allowed thermal treatments. The cell was connected to a vacuum manifold for the various treatments and was transferred to the sample compartment of a Beckman IR 4250 infrared spectrometer for the IR measurements.

Before the spectra were recorded, the cell was evacuated for 15 min under vacuum of better than 10⁻⁴ torr at room temperature.

Thermogravimetric Measurements. These were made by using a classical Mac Bain system. The catalyst was also used as a wafer which was placed in a small cup hung by a quartz spring the temperature of which was kept constant at 27 °C. The increase in the length of the spring was 1 mm per 0.83 mg, corresponding to 250 mm on the recorder. Sensitivity was ~0.05 mg for a catalyst mass of 200 mg. The cup and the spring were contained in an airtight tube which allowed the various treatments to be